

Department of Electronics and Communication Engineering

Syllabus for Ph.D Admission Eligibility Test

Section 1: Networks, Signals and Systems

Circuit analysis: Node and mesh analysis, superposition, Thevenin's theorem, Norton's theorem, reciprocity. Sinusoidal steady state analysis: phasors, complex power, maximum power transfer.

Linear 2-port network parameters, wye-delta transformation.

Continuous-time signals: Fourier series and Fourier transform, sampling theorem and applications.

Discrete-time signals: DTFT, DFT, z-transform, discrete-time processing of continuous-time signals. LTI systems: definition and properties, causality, stability, impulse response, convolution, poles and zeroes, frequency response, group delay, phase delay.

Section 2: Electronic Devices

Energy bands in intrinsic and extrinsic semiconductors, equilibrium carrier concentration, direct and indirect band-gap semiconductors.

Carrier transport: diffusion current, drift current, mobility and resistivity, generation and recombination of carriers. P-N junction, Zener diode, BJT, MOS capacitor, MOSFET, LED, photo diode and solar cell.

Section 3: Analog Circuits

Diode circuits: clipping, clamping and rectifiers.

BJT and MOSFET amplifiers: biasing, ac coupling, small signal analysis, frequency response.

Op-amp circuits: Amplifiers, summers, differentiators, integrators, active filters, Schmitt triggers and oscillators.

Section 4: Digital Circuits

Number representations: binary, integer and floating-point- numbers. Combinatorial circuits: Boolean algebra, minimization of functions using Boolean identities and Karnaugh map, logic gates and their static CMOS implementations, arithmetic circuits, code converters, multiplexers, decoders.

Sequential circuits: latches and flip-flops, counters, shift-registers, finite state machines, propagation delay, setup and hold time, critical path delay.

Data converters: sample and hold circuits, ADCs and DACs Semiconductor memories: ROM, SRAM, DRAM.

Computer organization: Machine instructions and addressing modes, ALU, data-path and control unit, instruction pipelining.

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Section 5: Communications

Random processes: autocorrelation and power spectral density, properties of white noise, filtering of random signals through LTI systems.

Analog communications: amplitude modulation and demodulation, angle modulation and demodulation, spectra of AM and FM, super hetero dyne receivers.

Information theory: entropy, mutual information and channel capacity theorem.

Digital communications: PCM, DPCM, digital modulation schemes (ASK, PSK, FSK, QAM), bandwidth, inter-symbol interference, MAP, ML detection, matched filter receiver, SNR and BER.

Fundamentals of error correction, Hamming codes, CRC.

Section 6: Electromagnetics

Maxwell's equations: differential and integral forms and their interpretation, boundary conditions, wave equation, Poynting vector.

Plane waves and properties: reflection and refraction, polarization, phase and group velocity, propagation through various media, skin depth.

Transmission lines: equations, characteristic impedance, impedance matching, impedance transformation, S- parameters, Smith chart.

Rectangular and circular waveguides, light propagation in optical fibers, dipole and monopole antennas, linear antenna arrays.